

Supplementary Information

Benzothiophene-flanked diketopyrrolopyrrole polymers: impact of isomeric frameworks on carrier mobilities

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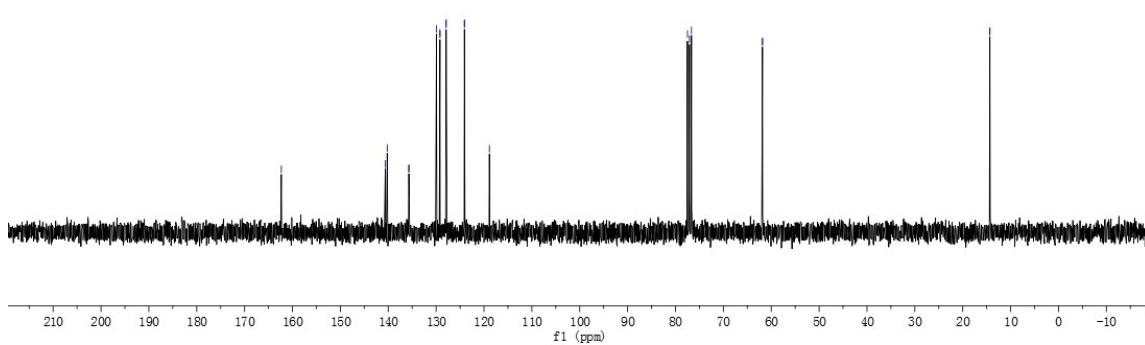
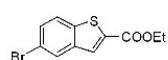
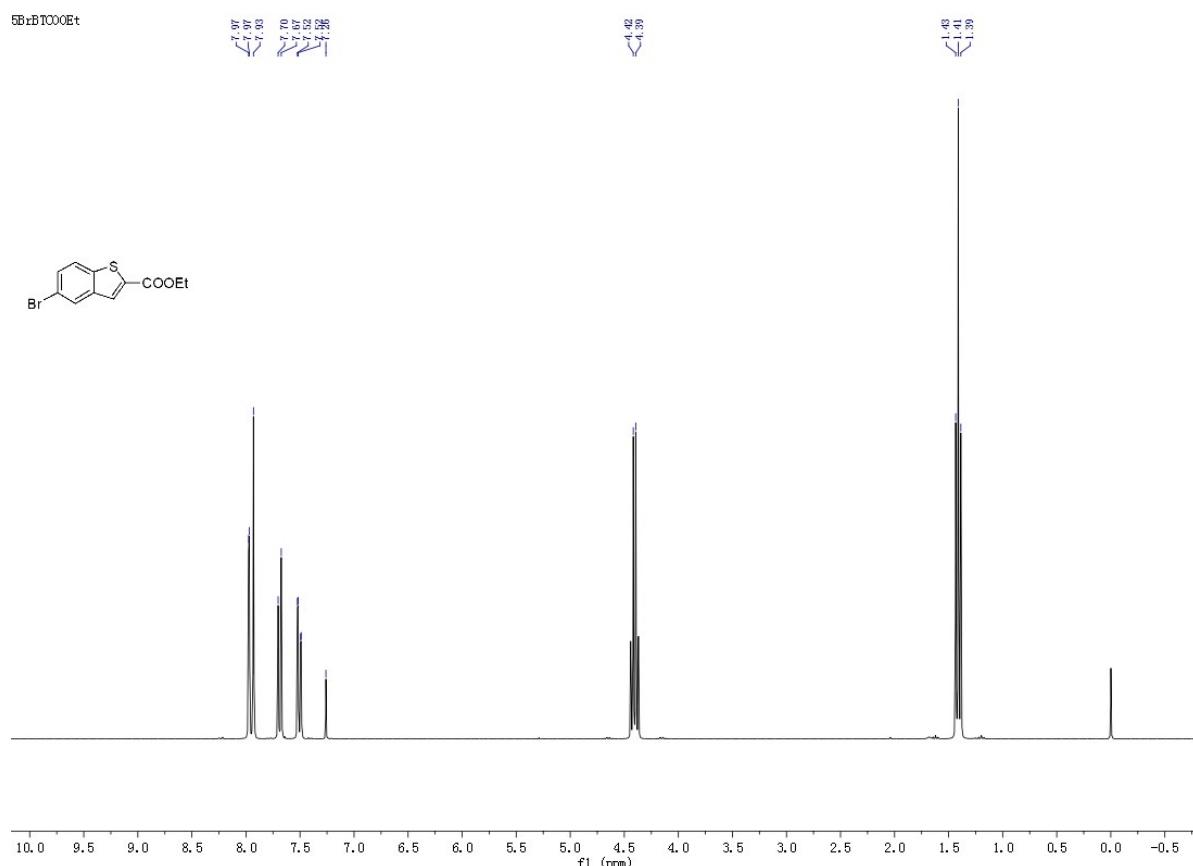
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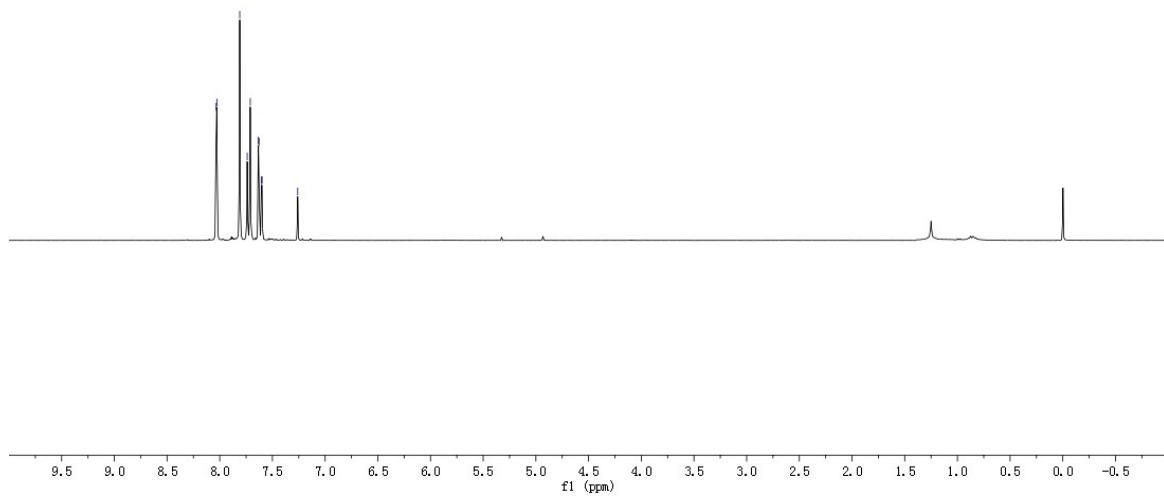
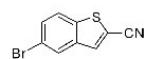
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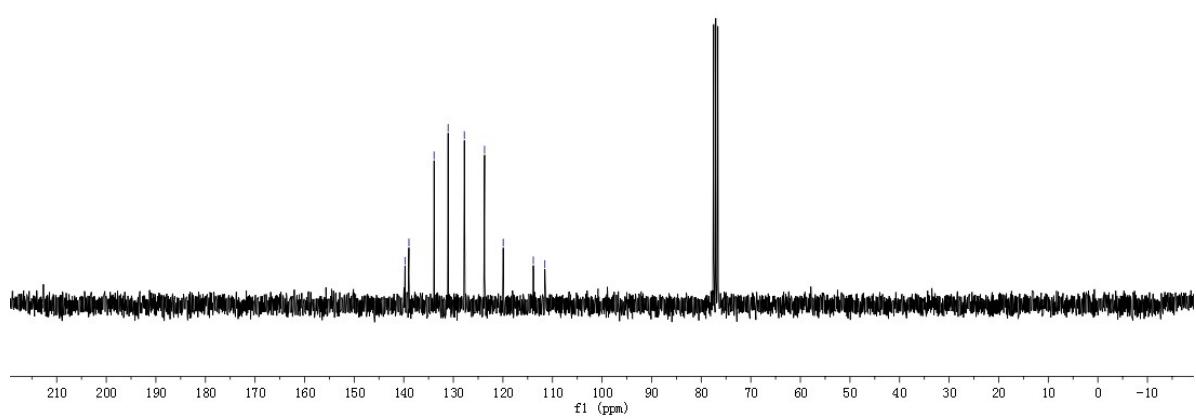
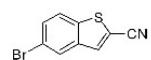
1. ^1H NMR and ^{13}C NMR spectra of new compounds

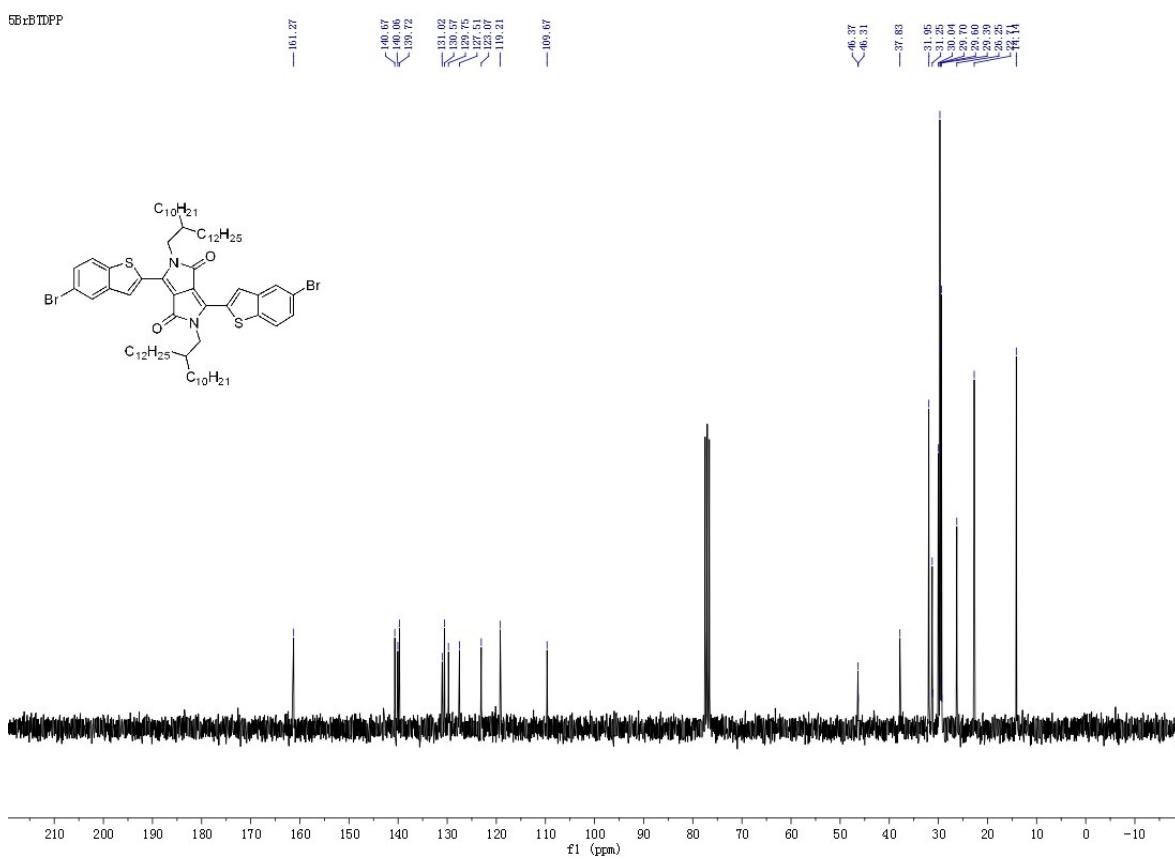
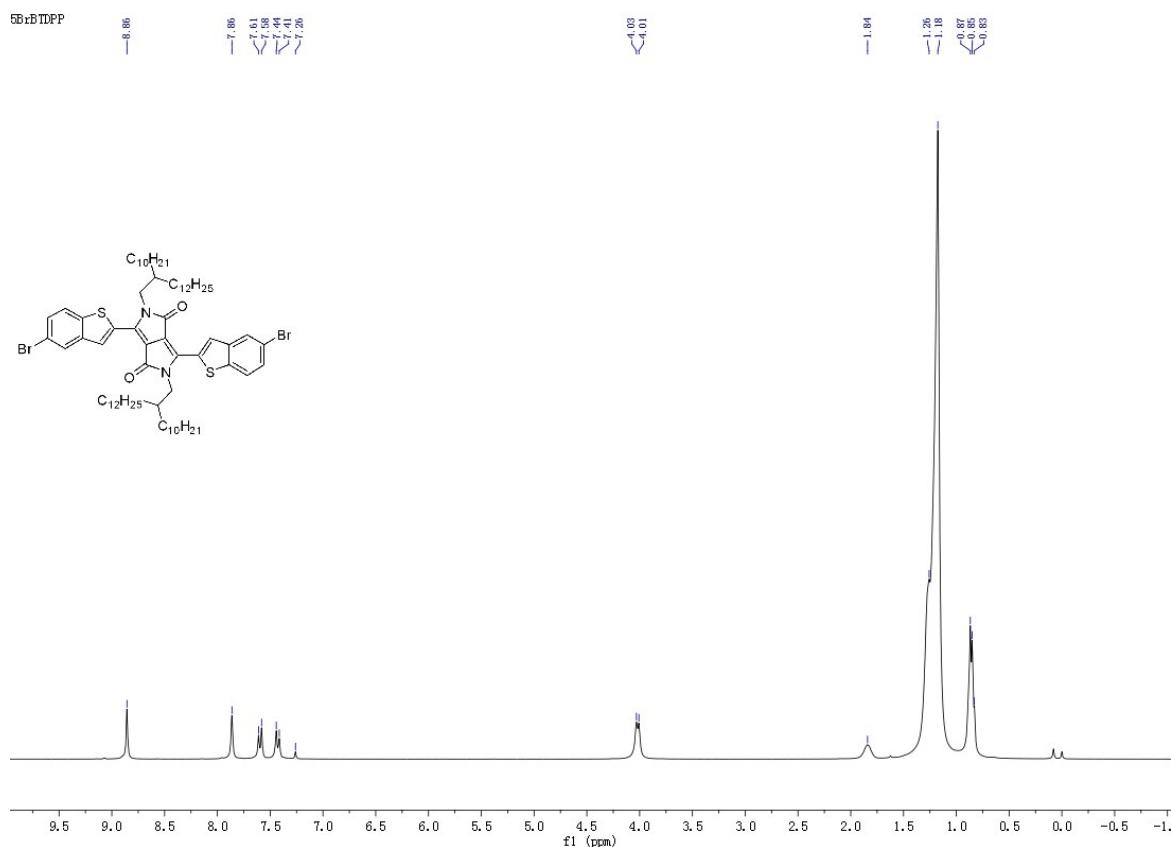


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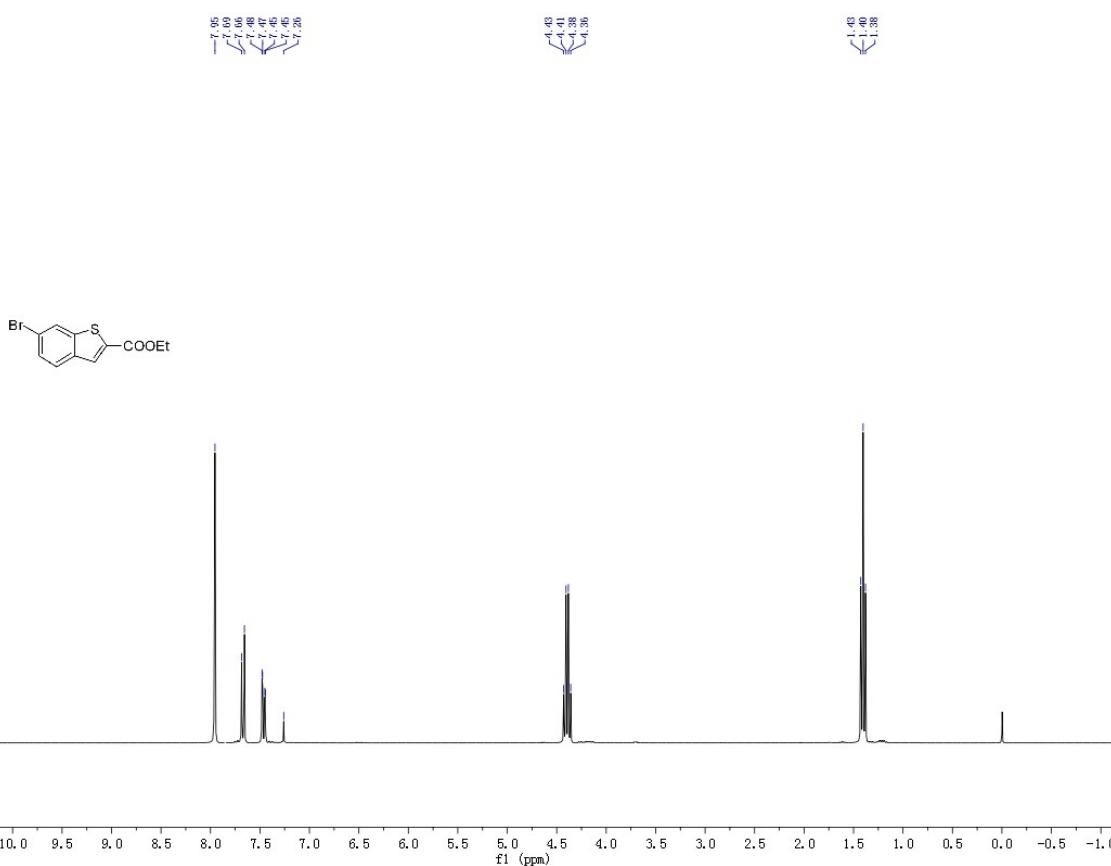


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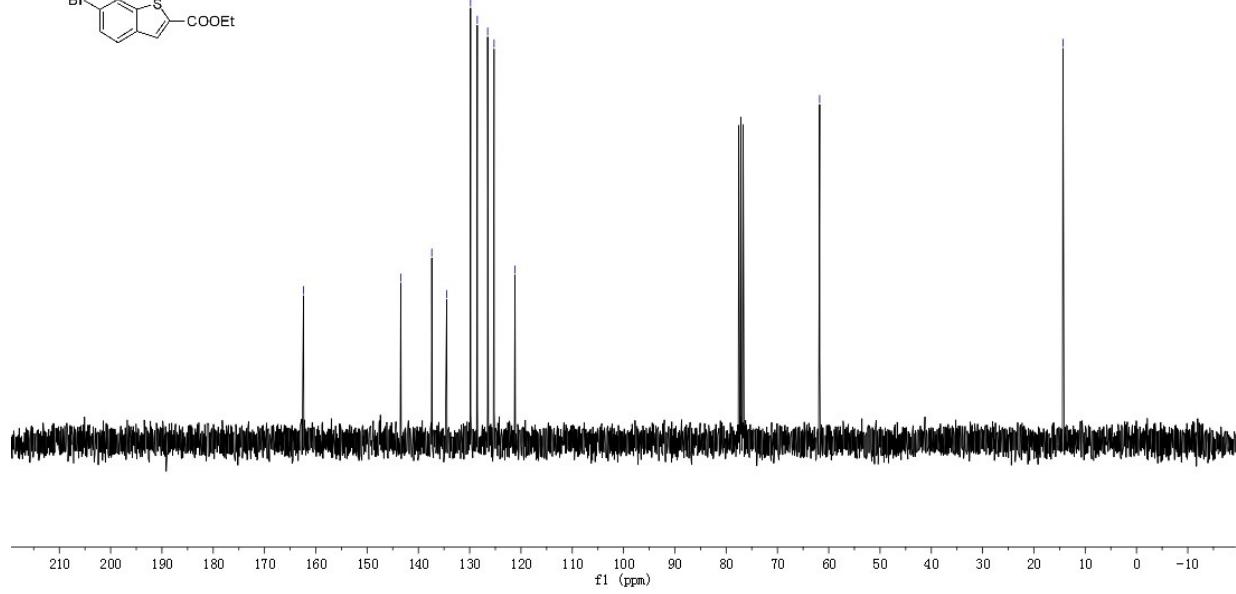
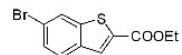
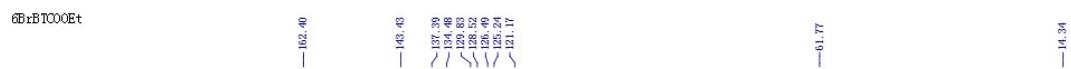




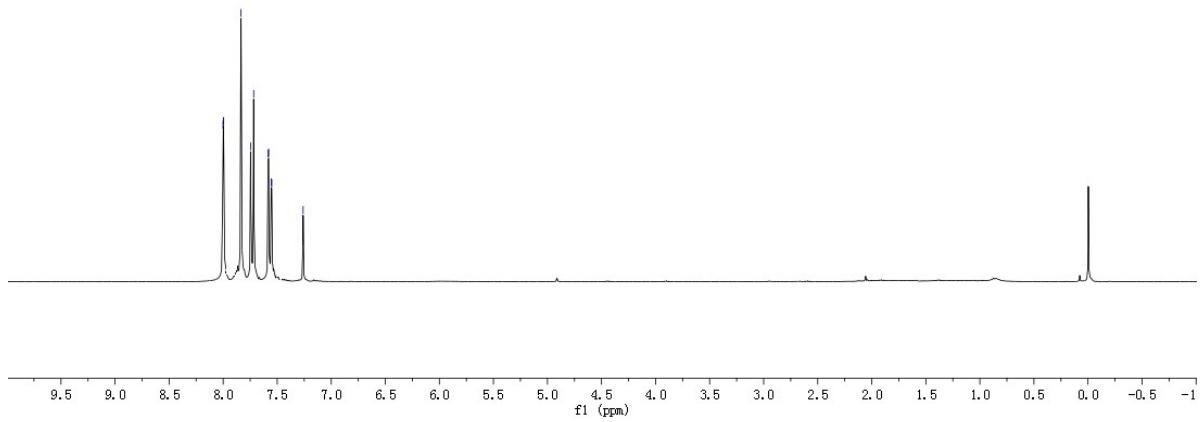
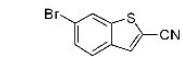
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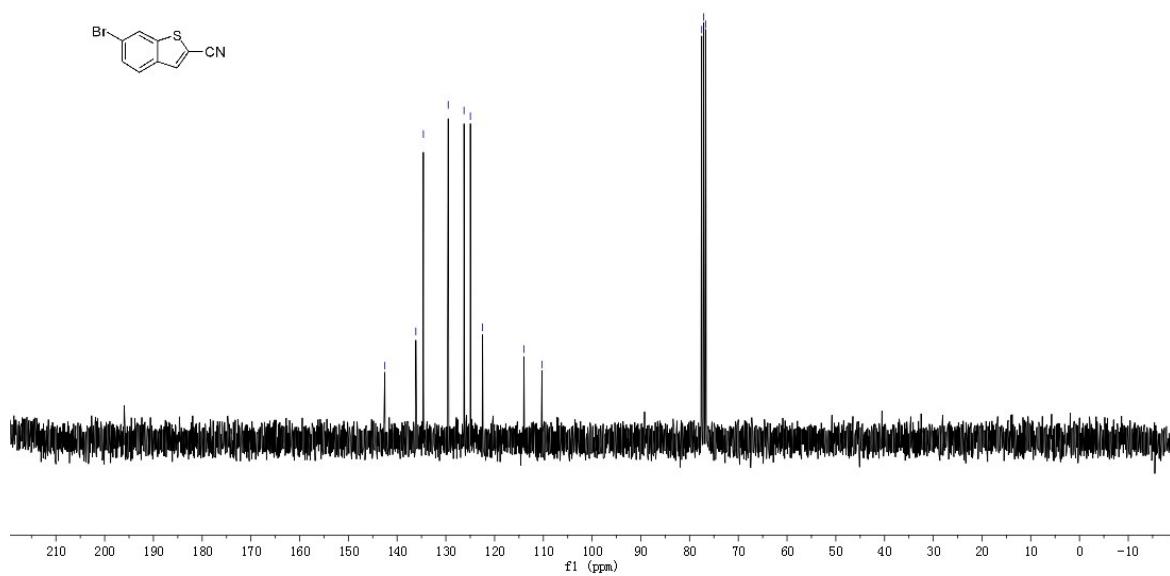
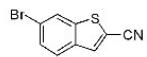
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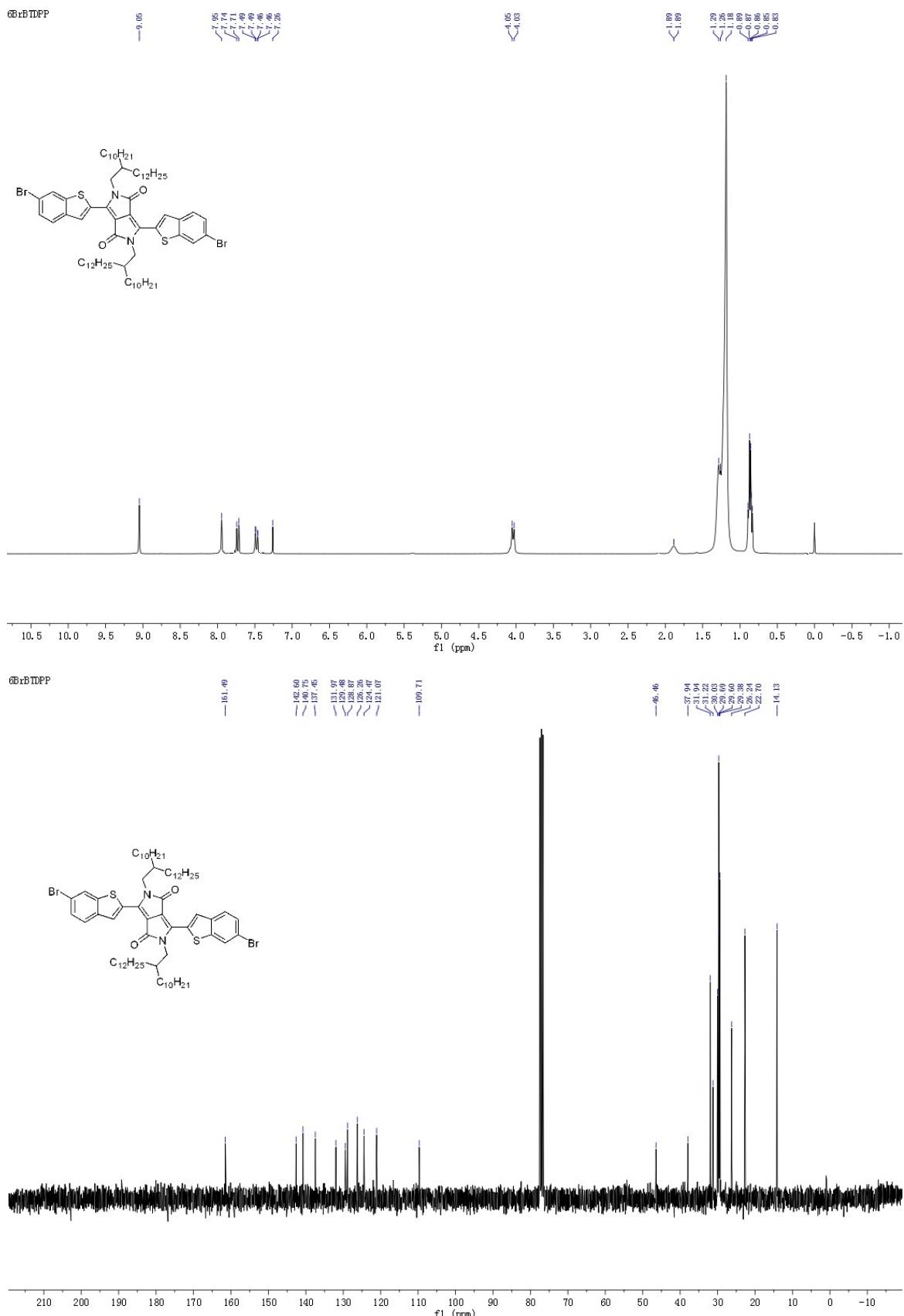


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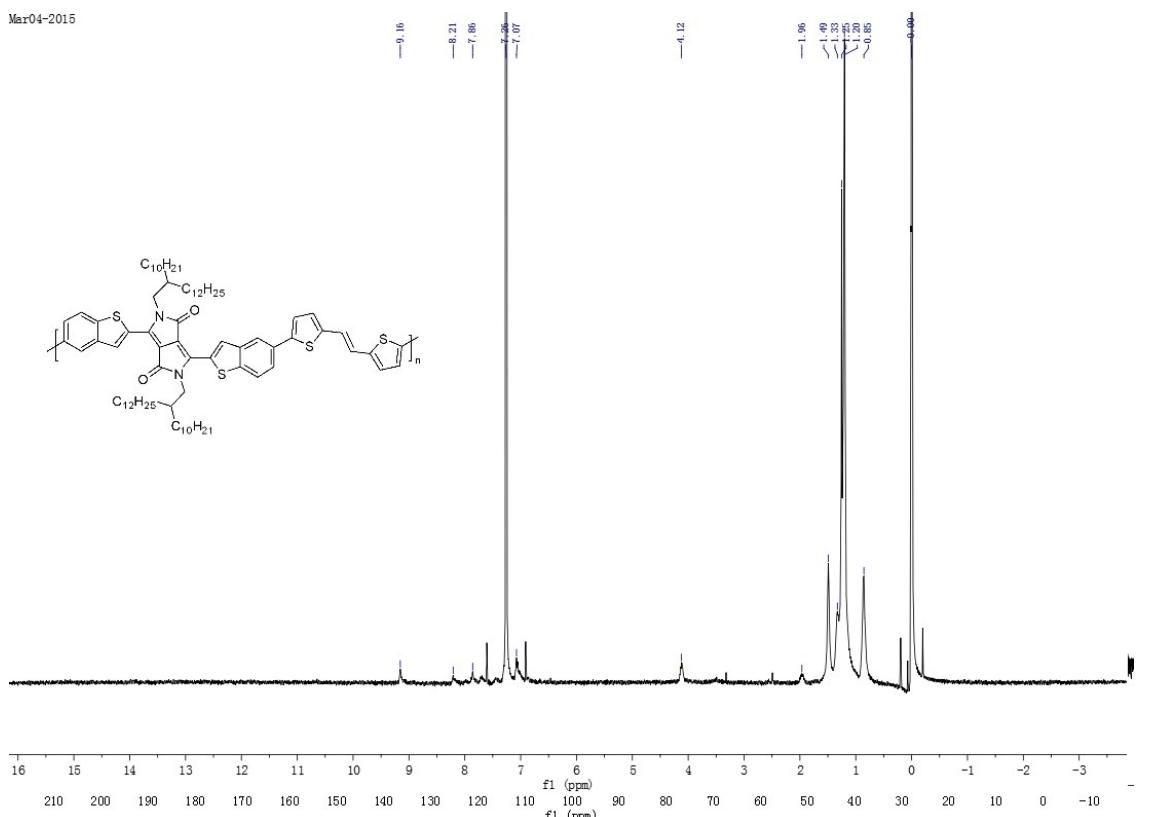


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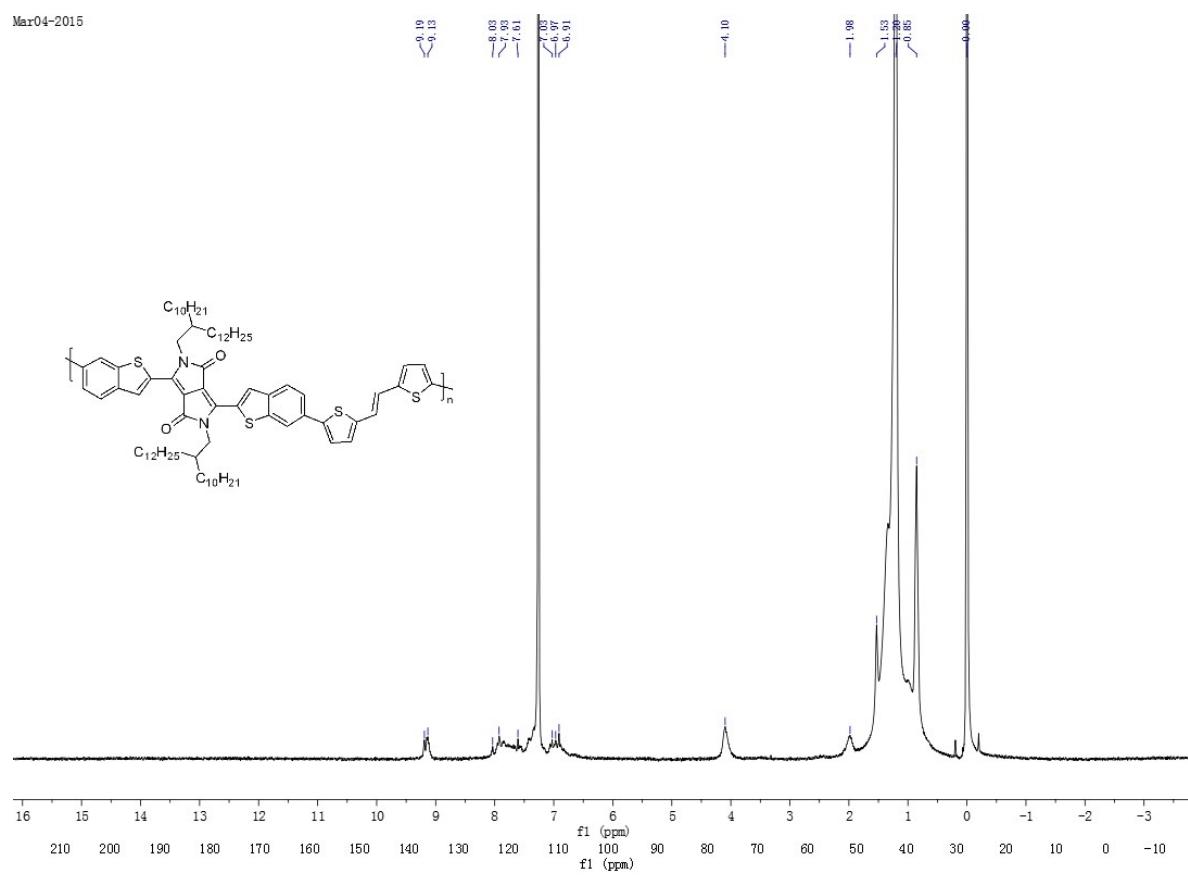




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2. Optical and electrochemical properties

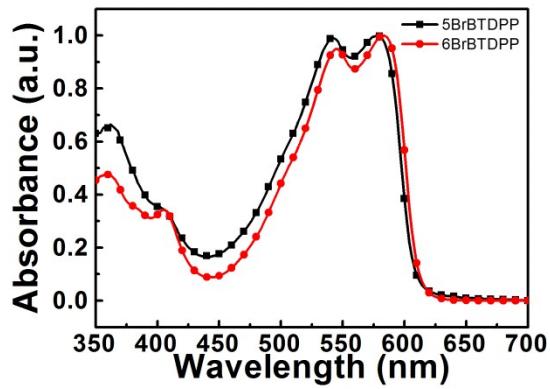


Fig. S1 UV-vis absorption spectra of the 5BrBTDP and 6BrBTDP monomers in dilute chloroform.

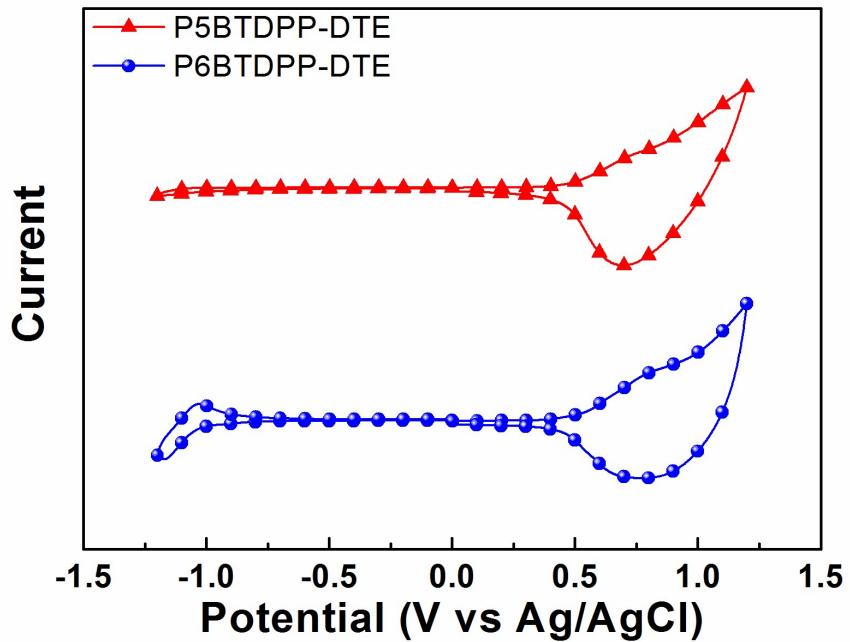


Fig. S2 Cyclic voltammograms of P5BTDP-DTE and P6BTDP-DTE using thin films drop-casted on a glassy carbon electrode as a working electrode in dichloromethane solution containing 0.1 M n-Bu₄NPF₆ as a supporting electrolyte.

Table S1 Summary of optical and electrochemical properties of P5BTDP-DTE and P6BTDP-DTE

Polymer	λ_{max} (nm)		E_g^{opt} (eV)	$E_{\text{red}}^{\text{onset}}$ (eV)	$E_{\text{ox}}^{\text{onset}}$ (eV)	E_{HOMO} (eV)	E_{LUMO} (eV)	E_g^{cv} (eV)
	soln.	film						
P5BTDP-DTE	586	582	1.60	-0.99	0.50	-4.90	-3.41	1.49
P6BTDP-DTE	632	644	1.56	-1.02	0.48	-4.88	-3.38	1.50

3. Field-effect characteristics

Table S2 Conditions for fabricating field-effect transistors

Compounds	Solvents	Concentration (mg/mL)	Rotating speed (r/min)	Annealing conditions (°C, min)
P5BrBTDP-DTE	<i>o</i> -DCB	10	1600, 1 min	160, 4
P6BrBTDP-DTE		5	1000-30s 2000-30s	160, 4

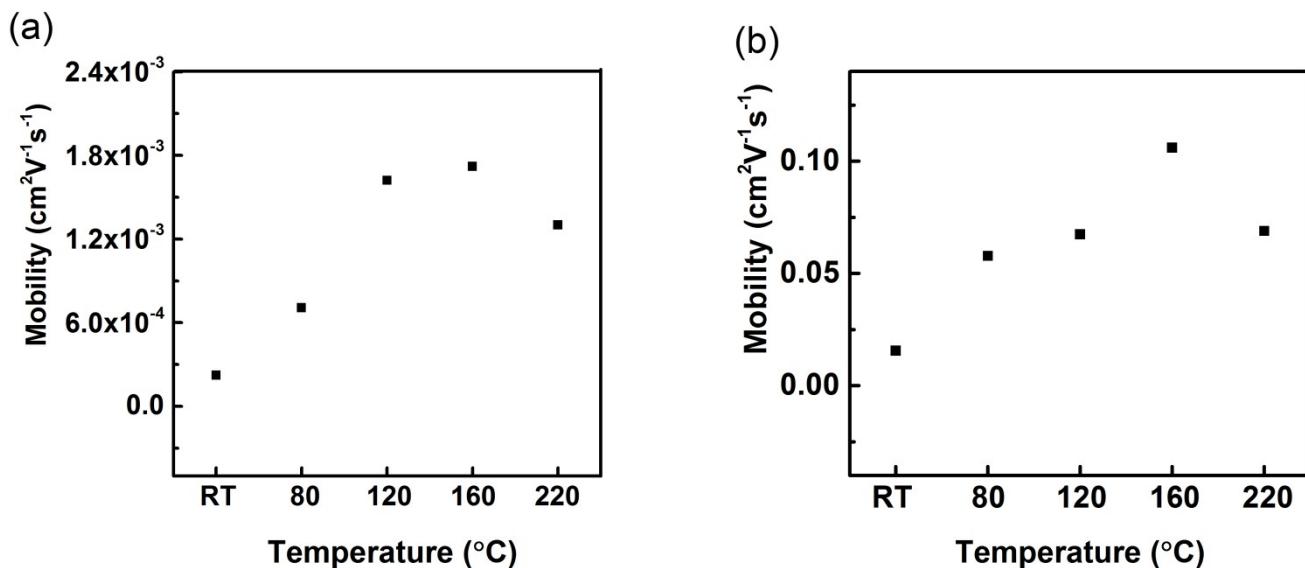


Fig. S3 A preliminary test of mobilities for each annealing temperatures. Both P5BTDP-DTE (a) and P6BTDP-DTE (b) tend to afford the best hole mobilities after annealing at 160°C.

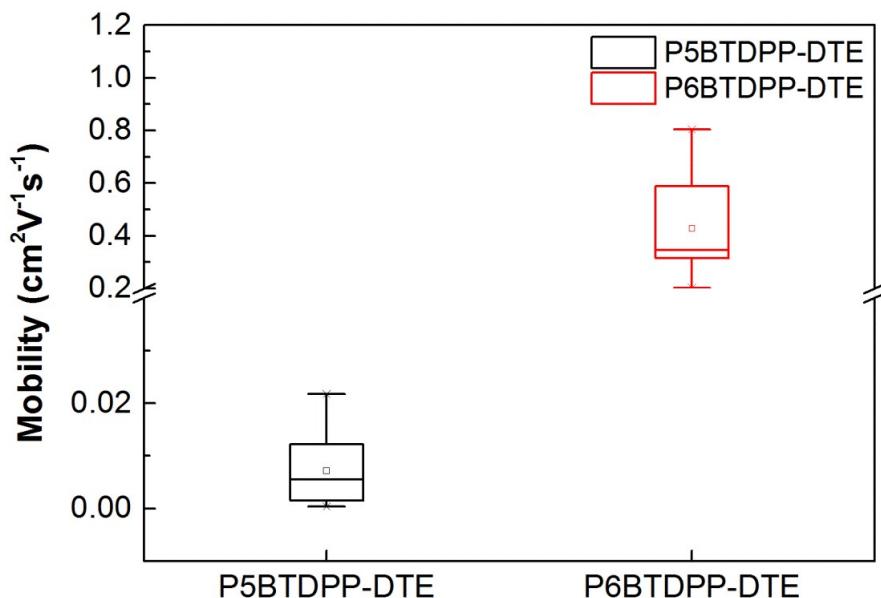


Fig. S4 Statistical display for distribution of mobilities of P5BTDP-DTE and P6BTDP-DTE based thin film transistors

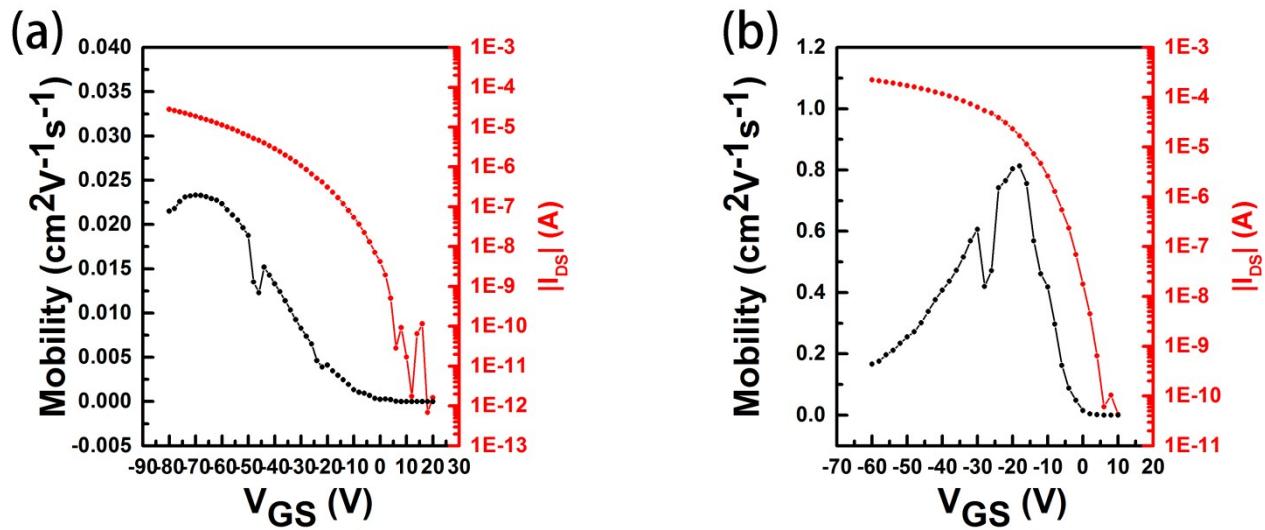


Fig. S5 Differential mobilities of two polymers: (a) P5BTDP-DTE, (b) P6BTDP-DTE.

4. GIXRD profiles

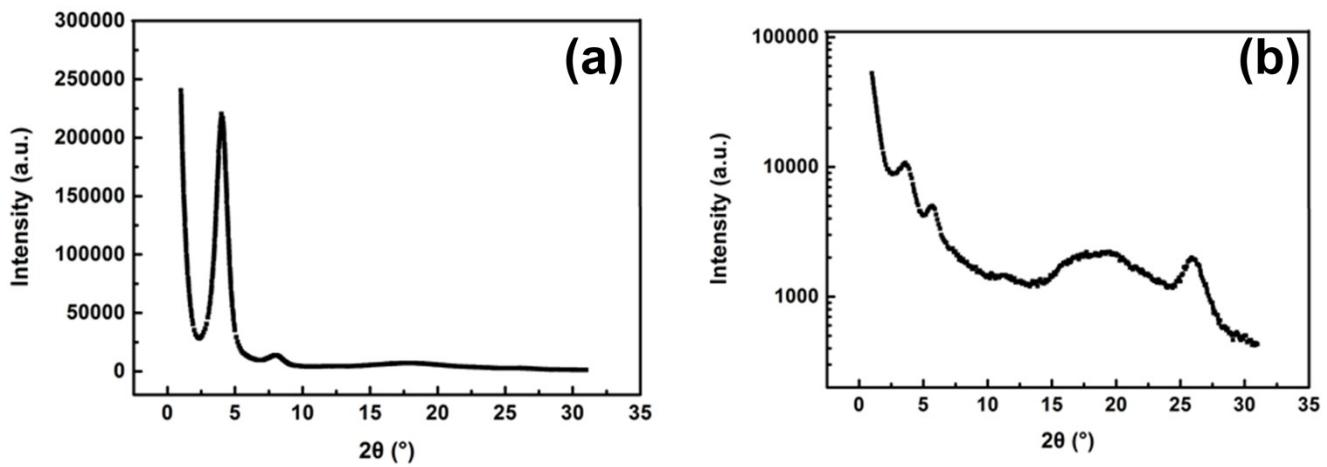


Fig. S6 One-dimensional GIXRD profiles of P5BTDP-DTE ($\lambda = 1.54 \text{ \AA}$): (a) out-of-plane, (b) in-plane.

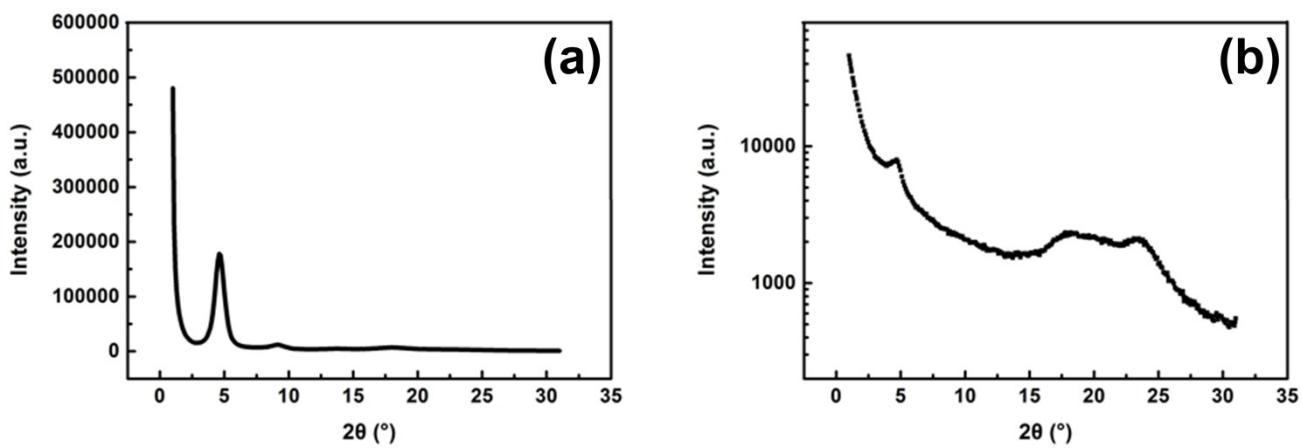


Fig. S7 One-dimensional GIXRD profiles of P6BTDP-DTE ($\lambda = 1.54 \text{ \AA}$): (a) out-of-plane, (b) in-plane.

5. AFM

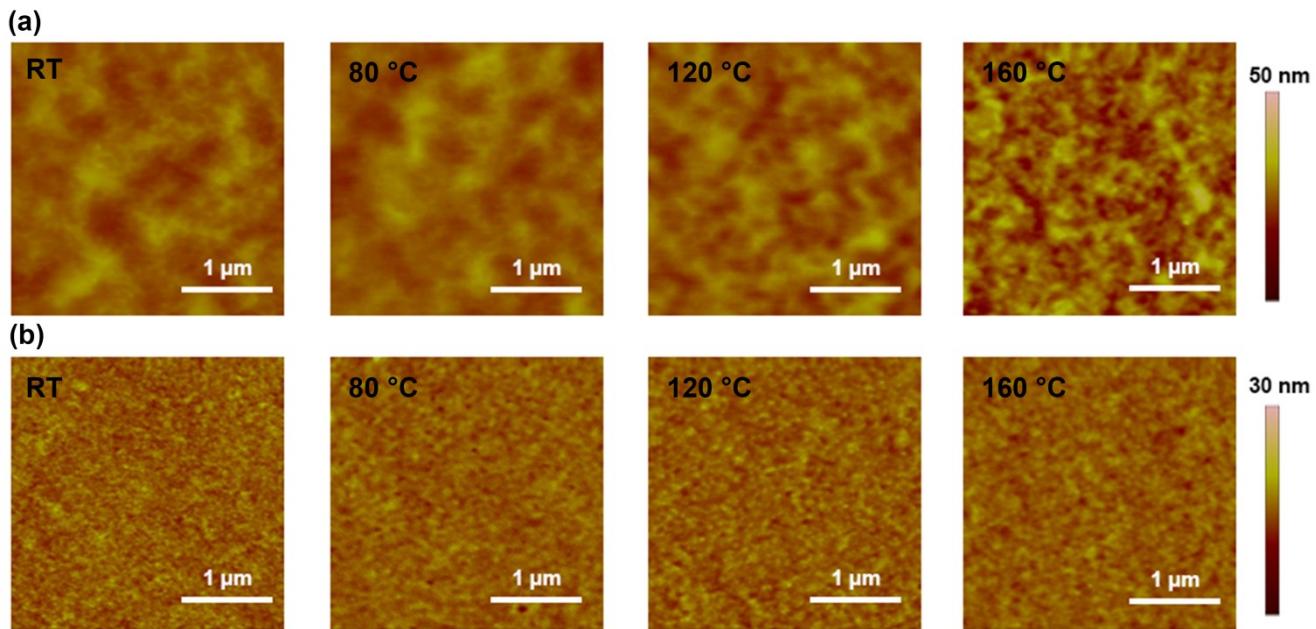


Fig. S8 AFM images of the (a) P5BTDP-DTE and (b) P6BTDP-DTE thin films.